85 9 Ö

2

1.6

0.26

3

Unit: mm

0.7

0.13

DSA9G01

Silicon NPN epitaxial planar type

For high-frequency amplification DSA5G01 in SSMini3 type package

Features

- High transition frequency f_T
- Halogen-free / RoHS compliant
- (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

Marking Symbol: A4

Packaging

Parameter	Symbol	Rating	Unit		1.0			
Collector-base voltage (Emitter open)	Vсво	-30	V	1: Base 2: Emitter				
Collector-emitter voltage (Base open)	Vceo	-20	V		3: Collector Panasonic SSMini3-F3-I			
Emitter-base voltage (Collector open)	Vebo	-5	V	JEITA SC-8 Code SOT-4				
Collector current	Ic	-30	mA				T-490	
Collector power dissipation	P _C	125	mW	Absolute Maximum Ratings $T_a = 25^{\circ}C$				
function temperature	Tj	150	°C	-	etrical			
Operating ambient temperature	Topr	-40 to +85	°C	■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$				
Storage temperature	T _{stg}	-55 to +150	°C					
Parameter	Symbol		Conditio	ons	Min	Тур	Max	Unit
Base-emitter voltage	V _{BE}	$V_{CE} = -10 V$	$V, I_{\rm C} = -1$	mA		- 0.7		V
Collector-base cutoff current (Emitter open)	Ісво	$V_{CB} = -10 V$	$V, I_E = 0$				- 0.1	μA
Collector-emitter cutoff current (Base open)	Iceo	$V_{CE} = -20 \text{ V}, I_B = 0$				-100	μA	
Emitter-base cutoff current (Collector open)	Іево	$V_{EB} = -5 \text{ V}, I_C = 0$				-10	μA	
Forward current transfer ratio *1	hFE	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}$		70		220		
Collector-emitter saturation voltage	VCE(sat)	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$			- 0.1		V	
Fransition frequency	f _T	$V_{CE} = -10 V$	$V, I_{\rm C} = -1$	mA	150	300		MHz
Reverse transfer capacitance (Common emitter)	C _{re}	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 10.7$ MHz			1.0		pF	

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Noise figure	NF	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 5 \text{ MHz}$	2.8	dB
Reverse transfer impedance	Zrb	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 2 \text{ MHz}$	22	W

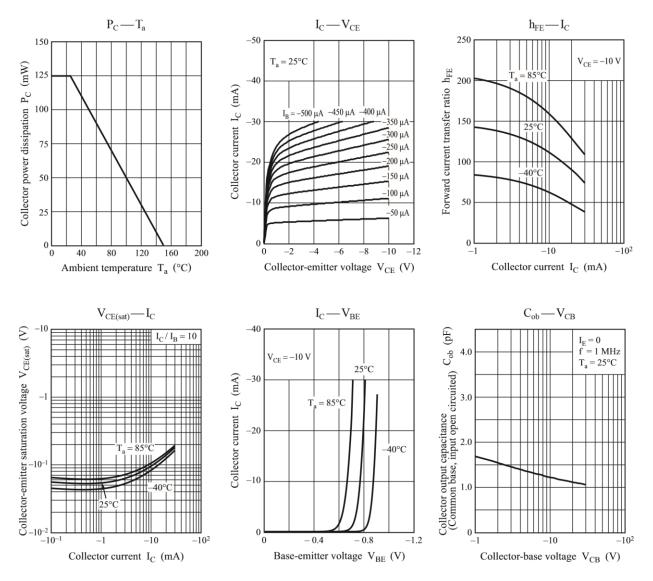
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

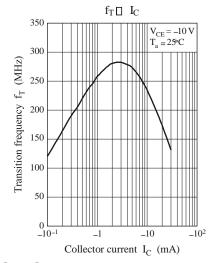
2. *1: Rank classification

Code	В	С	0
Rank	В	С	No-rank
hfe	70 to 140	110 to 220	70 to 220
Marking Symbol	A4B	A4C	A4

Product of no-rank is not classified and have no marking symbol for rank.

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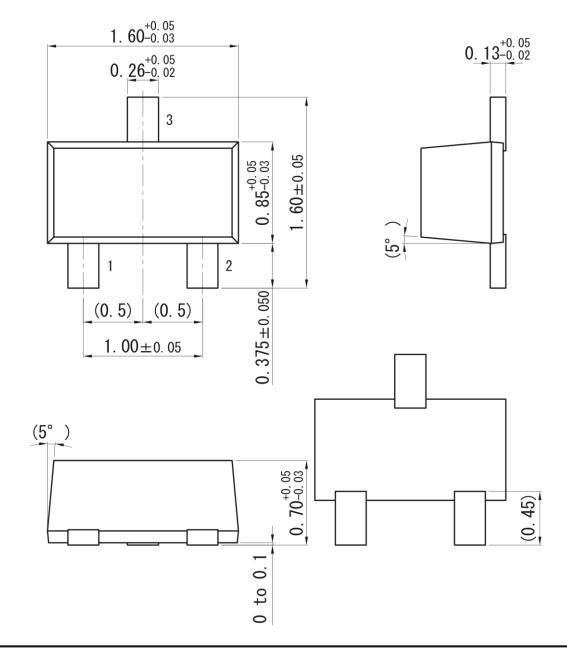




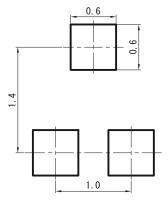
DSA9G01

SSMini3-F3-B

Unit: mm



Land Pattern (Reference) (Unit: mm)



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